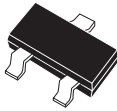


CMPT3640

PNP SILICON TRANSISTOR



SOT-23 CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMPT3640 type is an PNP silicon transistor manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for saturated switching applications.

Marking code is C2J.

MAXIMUM RATINGS (T_A=25°C)

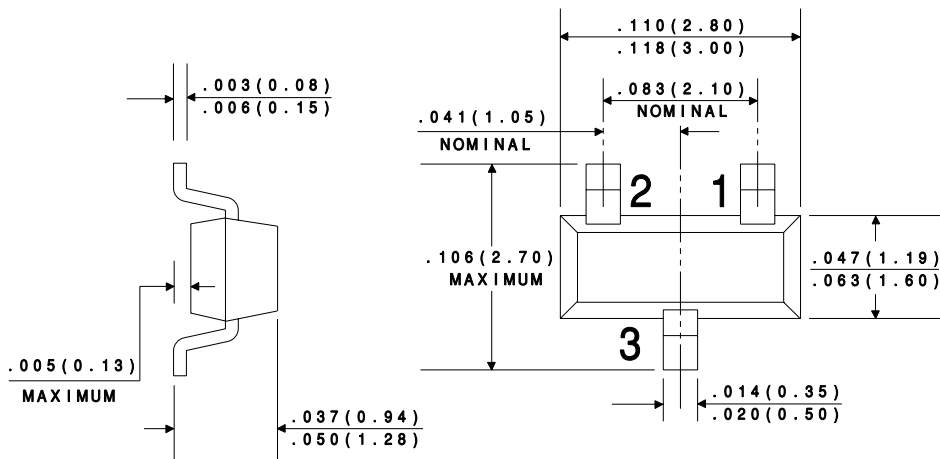
| | SYMBOL | | UNITS |
|---------------------------|-----------------------------------|-------------|-------|
| Collector-Base Voltage | V _{CB0} | 12 | V |
| Collector-Emitter Voltage | V _{CEO} | 12 | V |
| Emitter-Base Voltage | V _{EBO} | 4.0 | V |
| Collector Current | I _C | 80 | mA |
| Power Dissipation | P _D | 350 | mW |
| Operating and Storage | | | |
| Junction Temperature | T _J , T _{stg} | -65 to +150 | °C |
| Thermal Resistance | θ _{JA} | 357 | °C/W |

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

| SYMBOL | TEST CONDITIONS | MIN | MAX | UNITS |
|----------------------|---|------|------|-------|
| I _{CES} | V _{CE} =6.0V | | 10 | nA |
| I _{CES} | V _{CE} =6.0V, T _A =65°C | | 10 | μA |
| I _B | V _{CE} =6.0V, V _{EB} =0 | | 10 | nA |
| BV _{CB0} | I _C =100μA | 12 | | V |
| BV _{CEO} | I _C =10mA | 12 | | V |
| BV _{EBO} | I _E =100μA | 4.0 | | V |
| V _{CE(SAT)} | I _C =10mA, I _B =1.0mA | | 0.20 | V |
| V _{CE(SAT)} | I _C =50mA, I _B =5.0mA | | 0.60 | V |
| V _{CE(SAT)} | I _C =10mA, I _B =1.0mA, T _A =65°C | | 0.25 | V |
| V _{BE(SAT)} | I _C =10mA, I _B =0.5mA | 0.75 | 0.95 | V |
| V _{BE(SAT)} | I _C =10mA, I _B =1.0mA | 0.80 | 1.00 | V |
| V _{BE(SAT)} | I _C =50mA, I _B =5.0mA | | 1.50 | V |
| h _{FE} | V _{CE} =0.3V, I _C =10mA | 30 | 120 | |

| SYMBOL | TEST CONDITIONS | MIN | MAX | UNITS |
|-----------|---|-----|-----|-------|
| h_{FE} | $V_{CE}=1.0V, I_C=50mA$ | 20 | | |
| f_T | $V_{CE}=5.0V, I_C=10mA, f=100MHz$ | 500 | | MHz |
| C_{ob} | $V_{CB}=5.0V, I_E=0, f=1.0MHz$ | | 3.5 | pF |
| C_{ib} | $V_{BE}=0.5V, I_C=0, f=1.0MHz$ | | 3.5 | pF |
| t_d | $V_{CC}=6.0V, V_{BE}=1.9, I_C=50mA, I_{B1}=5.0mA$ | | 10 | ns |
| t_r | $V_{CC}=6.0V, V_{BE}=1.9, I_C=50mA, I_{B1}=5.0mA$ | | 30 | ns |
| t_s | $V_{CC}=6.0V, I_C=50mA, I_{B1}=I_{B2}=5.0mA$ | | 20 | ns |
| t_f | $V_{CC}=6.0V, I_C=50mA, I_{B1}=I_{B2}=5.0mA$ | | 12 | ns |
| t_{on} | $V_{CC}=6.0V, V_{BE}=1.9, I_C=50mA, I_{B1}=5.0mA$ | | 25 | ns |
| t_{on} | $V_{CC}=1.5V, I_C=10mA, I_{B1}=0.5mA$ | | 60 | ns |
| t_{off} | $V_{CC}=6.0V, V_{BE}=1.9, I_C=50mA, I_{B1}=5.0mA$ | | 35 | ns |
| t_{off} | $V_{CC}=1.5V, I_C=10mA, I_{B1}=I_{B2}=0.5mA$ | | 75 | ns |

All dimensions in inches (mm).



LEAD CODE:

- 1) BASE
- 2) EMITTER
- 3) COLLECTOR



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